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## ARTICLE

## Efficient Organic Inorganic Hybrid Perovskite Solar Cells Processed in Air

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Cite this: DOI: 10.1039/x0xx00000x

Received 00th January 2012,  
Accepted 00th January 2012

DOI: 10.1039/x0xx00000x

www.rsc.org/

**Abstract:** Organic-inorganic hybrid perovskite solar cells with: fluorine doped tin oxide/ titanium dioxide /  $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x$  / poly (3-hexylthiophene)/silver were made in air with more than 50% humidity. The best devices showed an open circuit voltage of 640mV, a short circuit current density of 18.85 mA /cm<sup>2</sup>, a fill factor of 0.407 and a power conversion efficiency of 5.67%. The devices showed external quantum efficiency varying from 60 to 80 % over a wavelength region of 350 nm to 750 nm of the solar spectrum. The morphology of perovskite was investigated using scanning electron microscopy and it was found to be porous in nature. This study provides insights for air-stability of perovskite solar cells.

## Introduction

Organic-inorganic hybrid perovskite materials are of great interest for optoelectronic applications. Recently, light emitting diodes and field effect transistors based on perovskite have been reported, where the perovskite was synthesized by mixing methyl ammonium iodide ( $\text{CH}_3\text{NH}_3\text{I}$ ) and lead iodide in organic solvents followed by annealing [1,2]. This was followed by reports of photovoltaic properties of the same material in dye sensitized solar cells [3-6]. Perovskite materials based on methyl ammonium iodide mixed with lead iodide are widely used as an active material in perovskite solar cells as it can be solution processed and are cost effective. Over the last few years, this material and its derivatives have delivered power conversion efficiency (PCE) exceeding 19%, [7] which generated a lot of interest in the solid state dye sensitised photovoltaic research community.

Even though  $\text{CH}_3\text{NH}_3\text{PbI}_3$  based cells have shown promise and very high PCE's, they are found to be unstable and tend to undergo fast degradation in performance in the presence of an electrolyte [3,8]. It is reported that the hygroscopic property of methyl ammonium cation makes it difficult to process solar cells in ambient air conditions using this material, without the use of an inert atmosphere. Additionally, these cells require a nano structured or a mesoporous layer of  $\text{TiO}_2$  for electron extraction resulting in a high performance [5,8-10]. A new mixed halide perovskite material,  $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x$ , used an  $\text{Al}_2\text{O}_3$  scaffold instead of a mesoporous  $\text{TiO}_2$  layer, which gave high performances with a boost in open circuit voltage resulting in a PCE above 10%. [9,11-14]

The mixed halide  $\text{CH}_3\text{NH}_3\text{Pb}_{3-x}\text{Cl}_x$  perovskite was found to be more stable and at the same time, have better carrier transport properties than the  $\text{CH}_3\text{NH}_3\text{PbI}_3$  perovskite material [15]. Furthermore,  $\text{CH}_3\text{NH}_3\text{Pb}_{3-x}\text{Cl}_x$  perovskite was found to exhibit ambipolar transport behaviour, which aided in developing simple planar structured cells, with an extremely thin absorber (ETA) layer. Simultaneously, a solid state hole transporting (HTM) material, Spiro-MeOTAD (2,2',7,7'-tetrakis(N,N-di-p-methoxyphenylamine)-9,9'-spirobifluorene) was used in these cells as it can penetrate through the porous perovskite layer and provide a better contact for charge transportation [3,9,16,17]. Other alternatives and less costly organic HTM materials like Poly tri-aryl amine (PTAA), Poly (3-hexylthiophene-2,5-diyl) (P3HT) and inorganic materials such as Copper Iodide (CuI) have also been used in the past [18-25] and high performance devices were achieved. One of the challenges in making solution processed devices is their fast degradation in the presence of moisture in the atmosphere.

In this article, an organic inorganic mixed halide perovskite solar cell with  $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x$  as an extremely thin absorber material and P3HT as a HTM over a thin film layer of dense  $\text{TiO}_2$  as an electron transport material (ETM) is reported. The devices were made in ambient air conditions with humidity greater than 50%. Most of the reported high efficiency solution processed perovskite based photovoltaic devices were fabricated in controlled atmosphere conditions with water and oxygen contents less than 1 ppm levels. An undoped P3HT was used as a hole transporting layer as our recent modelling studies have revealed that such an undoped hole transporting layer can enhance the photovoltaic properties of perovskite solar cells.



## Experimental Methods

### Device Fabrication

Fluorine-doped tin oxide (FTO) glasses (Pilkington) were cleaned by ultrasonication in ethanol for 30 minutes and treated in a UV Ozone cleaner for 30 min. The cleaned FTO glasses were coated with 0.15 M titanium diisopropoxide bis(acetylacetonate) (75% by wt in isopropanol, Aldrich) in 1-butanol (Aldrich) solution by the spin-coating method at 2000 rpm for 60 s, followed by heating at 125° C. The films were cooled down to room temperature and a 0.3 M titanium diisopropoxide bis(acetylacetonate) solution in 1-butanol was spin coated. The procedure was repeated twice to make a pin hole free dense TiO<sub>2</sub> film [8]. The substrates were annealed in a box furnace at 450° C for 60 minutes. The perovskite sensitizer CH<sub>3</sub>NH<sub>3</sub>I was prepared according to the reported procedure [26]. A mixture of hydroiodic acid (57 wt.% in water, Aldrich) and methylamine (40% in methanol, Aldrich) were stirred in an ice bath for 2 hours. After stirring at 0° C for 2 hours, the resulting solution was evaporated at 50° C for 1 hour and methyl ammonium iodide was obtained. The precipitate was washed three times with diethyl ether and dried under vacuum in dark conditions.

For preparing the CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3-x</sub>Cl<sub>x</sub> layer, methylammonium iodide (CH<sub>3</sub>NH<sub>3</sub>I) and lead (II) chloride (PbCl<sub>2</sub>, Aldrich) were dissolved in anhydrous N,N-dimethyl formamide (DMF, Aldrich) mixed in a 3:1 molar ratio of CH<sub>3</sub>NH<sub>3</sub>I to PbCl<sub>2</sub>, to make the 30% and 40% by weight precursor solutions. The 40 wt% and 30 wt% solutions were spin coated at 2000 rpm and 1500 rpm respectively for 45 s to make perovskite films of uniform thickness for device performance comparison. The substrates were subsequently heated at 100° C on a hot plate, under dark conditions, for 90 minutes [27]. The hole transporting layer of Poly (3-hexylthiophene-2,5-diyl) (P3HT) was prepared by spin coating a 15 mg/mL solution in chlorobenzene at 1500 rpm for 2 min. The substrates were loaded into a vacuum thermal evaporator and a 120 nm thick layer of silver (Ag) was thermally evaporated as counter electrode at a pressure of 6 x 10<sup>-6</sup> mbar. A number of devices were made for making a statistical comparison. The thickness of each layer was measured using a Dektak 6M stylus profilometer. The thickness of each layer of the optimized device with a correction factor of ± 5 nm is as follows TiO<sub>2</sub> blocking layer ~ 120 nm, Perovskite layer ~ 250 nm, P3HT layer ~ 100 nm and Ag layer ~ 120 nm. The active area of the device is 0.09 cm<sup>2</sup>.

### Measurements and characterizations:

X-ray diffraction pattern of perovskite was measured on X-Pert Pro Analytical diffractometer. Morphology and microstructure characterizations were performed using a field emission scanning electron microscope (Nova NanoSEM NPE 206 high resolution SEM). The coverage of the perovskite was calculated by processing scanning electron microscope image of the film using greyscale threshold method in open source

software, ImageJ [28]. UV-Vis absorption spectra were acquired using a SHIMADZU UV-3600 spectrophotometer. The current-voltage characteristics of the devices were measured with a Keithley 6430 source meter in dark and under an illumination of 1000W/m<sup>2</sup> AM1.5G spectrum using an Oriel 3A solar simulator tested with a NREL calibrated silicon solar cell. The external quantum efficiency (EQE) measurements were done using a lock-in technique with a 250 W xenon lamp coupled with a Newport monochromator and chopped at 40 Hz with a light chopper blade as light source. A lock-in amplifier (SRS 830, Stanford Research Systems Inc. USA) was used to measure currents and a NIST calibrated silicone photodiode was used to find the incident power spectral response of the incident light. The measurements were done using shadow masks to avoid edge effects and proper mismatch factor was taken to square off the spectral mismatch for calculating PCE and EQE [29, 30].

## Results and Discussion

Mixed halide perovskite was spin coated in ambient conditions, on a plane glass plate and was observed. The film was transparent before annealing and turned to dark brown upon annealing as shown in Figure 1. Unlike CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub>, the mixed halide perovskite remained in the same state without any change for more than one month when coated with a layer of P3HT and is confirmed using the UV-Vis studies of bilayer CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3-x</sub>Cl<sub>x</sub>/P3HT structures. The UV-Vis absorbance spectrum of the bilayer CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3-x</sub>Cl<sub>x</sub>/P3HT, single layers of CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3-x</sub>Cl<sub>x</sub> and P3HT of similar thickness as used in optimized device structure is as shown in Figure 2(a). The absorption of CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3-x</sub>Cl<sub>x</sub>/P3HT bilayer of film thickness similar to that of the actual device shows features of both P3HT and perovskite. P3HT has an absorption edge at wavelength (λ) ~ 640 nm with shoulder at λ ~ 600 nm and a peak at λ ~ 520 nm. The perovskite showed a broad absorption with an edge at λ ~ 800 nm and a peak at λ ~ 450 nm. Even though a perovskite layer of thickness 250 nm should absorb all the light incident on it due to an absorption coefficient of ~ 10<sup>5</sup> cm<sup>-1</sup> [31], poor coverage of perovskite films make light to pass through it and results in absorption contribution from P3HT in the bilayer structure. The SEM images (Figure 2(c) and Figure 2(d)) of mixed halide perovskite show the porous nature of the CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3-x</sub>Cl<sub>x</sub> film validating the reason for P3HT contribution in the UV-Vis spectrum of bilayer structure. The needle structure of the perovskite as seen from the SEM image can be attributed to the increased absorbance of the perovskite film in the longer wavelength region due to increased internal scattering in such kind of structures.[25]

The absorption data of perovskite/P3HT bilayer coated on a plane glass plate of similar thickness as in the actual device (made at the time of device fabrication) is compared with absorption spectra of actual device FTO/TiO<sub>2</sub>/Perovskite/P3HT/Ag (absorption were taken on device where Ag was not coated) after one month and of that after 6 months as shown in Figure 2b to study the stability of perovskite layer. The





absorption spectra of the bilayer after one month shows a change in the spectral envelope in the spectral region attributed to contribution from P3HT ( $450\text{ nm} < \lambda < 600\text{ nm}$ ) showing degradation of P3HT over time. The spectral envelope remain

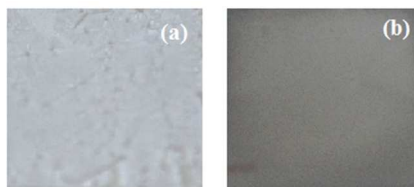


Figure 1-  $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x$  film (a) before and (b) after annealing in ambient atmospheric conditions, the film which was initially transparent was found to change into a dark grey colour, indicating the formation of  $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x$  after 45 minutes.

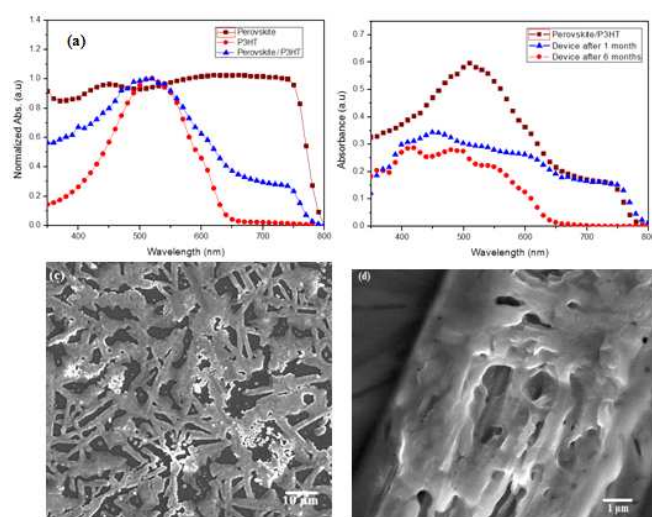


Figure 2 (a) comparison of UV-Vis absorption spectra of  $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x$  layer, P3HT layer and  $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x/\text{P3HT}$  bilayer; (b) comparison of UV-Vis absorption spectrum of  $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x/\text{P3HT}$  bilayer made on a glass along with the actual device fabrication, with UV-Vis absorption spectra of actual device FTO/ $\text{TiO}_2$ / $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x/\text{P3HT}/\text{Ag}$  after 1 month and device after 6 months. (Absorption cross section is selected in such a way that there is no Ag coating on top of P3HT) (c) Scanning electron microscopy (SEM) images of  $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x$  perovskite film and (d) film at higher magnification.

unchanged in the spectral window attributed to perovskite ( $650\text{ nm} < \lambda < 800\text{ nm}$  and  $\lambda < 450\text{ nm}$ ) and can be attributed to a stable perovskite layer. Further storage of the device in ambient condition over a period of 6 month showed degradation of perovskite layer and is attributed to the disappearance of the spectral features in the  $\lambda$  region from  $650\text{ nm}$  to  $800\text{ nm}$ . The X-ray diffraction analysis of the mixed halide perovskite shows characteristic peaks at  $14.1^\circ$  and  $28.5^\circ$  (Figure 3(c)). The X-ray analysis of the perovskite films, even after one month (Figure 3(d)) showed the same peaks with unaltered peak positions, thus illustrating that there is no significant degradation of the perovskite film with time. However, the films after 6 months, shows a change in peak position (Figure 3(e)), with a prominent peak at  $12.7^\circ$ , indicating the presence of  $\text{PbI}_2$ , due to the degradation of perovskite.[27] The film retained the same

morphology without any change, when stored for a period of more than a month. After confirming the stability of the perovskite by different methods, photovoltaic devices were made with the device structure: FTO/ $\text{TiO}_2$ / $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x/\text{P3HT}/\text{Ag}$ . A schematic of device structure and energy level diagram of different material used in the device is as shown in Figure 3a and Figure 3b respectively.

A  $\text{TiO}_2$  dense layer with a thickness of about  $120\text{ nm}$  was used as an electron transporting, hole blocking layer. It has been reported earlier that the mixed perovskite diffusion lengths for electrons and holes are typically, in the order of  $1\text{ micron}$ , with a good ambipolar behaviour.[15] The optimal thickness of perovskite was  $250\text{ nm}$ . Our recent dark I-V modelling study revealed that an undoped hole transporting layer is better for reducing the space charge effects [32]. Hence, one of the commonly used p-type polymers, P3HT, was employed herein, as the hole transporting layer in the devices. The P3HT film thickness was optimized at  $100\text{ nm}$  for highest efficiency devices. All these layers were solution processed in air; they were spin coated under ambient conditions with humidity levels in excess of  $50\%$ . One of the main factors affecting the performance of the perovskite solar cell is the thickness and the film quality of the active layer. The formation of pin-holes can cause the hole transport material and electron transport material to come in contact, resulting in the formation of parallel paths, causing high shunt resistance and recombination of electrons and holes. Even though better coverage is achieved over  $\text{TiO}_2$  by increasing the thickness of the  $\text{TiO}_2$  layer and the concentration of the perovskite precursor solution, the maximum coverage of the perovskite film is around  $95\%$  of the surface area only in literature [12, 26]. The SEM images of the perovskite active layer show decent coverage over the dense  $\text{TiO}_2$  layer and about  $75\%$  coverage at higher magnification with needle like structures Figure 2(c). The film was found to be porous in nature at higher magnification. (Figure 2(d))

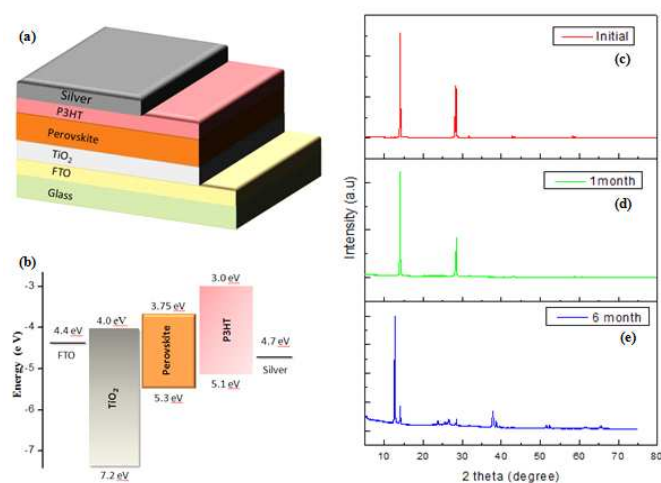


Figure 3. (a) Schematic device structure; (b) Energy level diagram of the different materials used in the device; (c) X-ray Diffraction (XRD) analysis plot of  $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x$  films at initial stage, (d) that after one month storage and (e) after 6 months storage.



The devices were made with different concentrations of  $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x$ . The dark current characteristic shows a diode like behaviour. The J-V (current density Vs voltage) characteristics were recorded under A.M.1.5G, 1Sun illumination (Figure 4(a)). The devices with 30% (by wt.) solution of the perovskite precursor gave a PCE of 4.79% with short circuit current density ( $J_{\text{sc}}$ ) of  $14.98 \text{ mA/cm}^2$ , open circuit voltage ( $V_{\text{oc}}$ ) of 781 mV and fill factor (FF) of 0.409. In order to enhance the solar cell performance, the concentration of the perovskite solution was increased to 40% (by wt.). When the process was repeated with 40% (by wt.) solution of the perovskite precursor, the PCE was observed to increase to 5.67% with  $J_{\text{sc}}$  of  $18.85 \text{ mA/cm}^2$ ,  $V_{\text{oc}}$  of 640mV and FF of 0.407. The  $J_{\text{sc}}$  was found to increase when the concentration of the solution was increased, the  $V_{\text{oc}}$  was found to decrease and the FF was found to be almost similar. The increase in  $J_{\text{sc}}$  is attributed to improvement in the absorption of perovskite layer made of 40 wt % solutions due to its better surface coverage. The perovskite films prepared from 40 wt% solution has a surface coverage of 75% and that made from 30 wt% solutions has a surface coverage of 63%. The  $V_{\text{oc}}$  decrease can be attributed to the intercalation of different layers into each other due to the porous nature of the active layer.

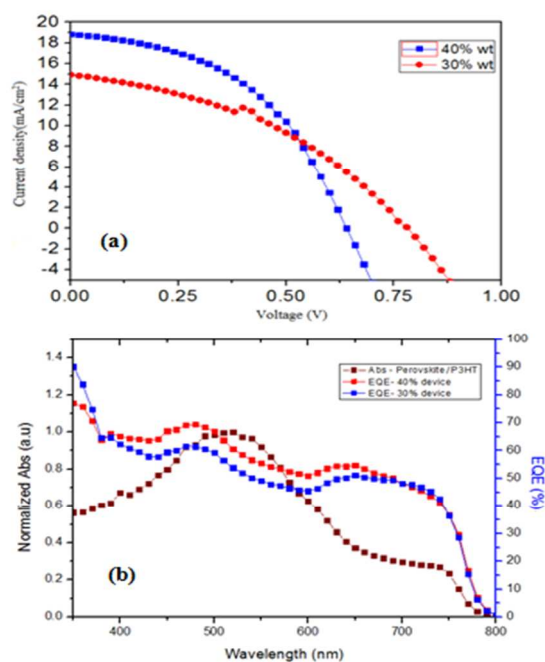


Figure 4. (a) J-V Characteristic of the devices made with 30% and 40% of  $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x$  (by wt.) precursor solution (b) EQE spectrum of solar cells made with 30% and 40% of  $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x$  (by wt.) precursor solution and UV-Vis absorbance spectra of  $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x/\text{P3HT}$  bilayer.

The PCE values are comparable to the values in literature obtained for solution processed perovskite solar cells which are made in controlled atmosphere. The EQE spectra (Figure 4(b)) showed the incident photon to current conversion efficiency varying from 60 to 80 % over a wavelength region of 350 to 750 nm of the solar spectrum with an edge extending to the

near- infrared region, to a wavelength of 800 nm. Comparison of EQE of the device and absorption spectra of  $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x/\text{P3HT}$  bilayer shows that the EQE of the device is resultant of photocurrent generation in P3HT and perovskite and the effective transport of free carriers to the electrode through these layers. It is to be noted that P3HT shows an excitonic feature resulting in the formation of excitons (bound electron hole pair) as the primary photoexcited species. But in perovskite, due to its high dielectric constant [33], free electrons and holes are created upon photoexcitation. In the  $\lambda$  ranging from 800 nm to 650 nm the photocurrent is due to that of perovskite. The electrons and holes which are formed in the perovskite, especially near the  $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x/\text{P3HT}$  interface, are well transferred to the electrodes through perovskite and hole transporting P3HT. There is a significant light harvesting in this  $\lambda$  region with a reduced ratio of EQE ratio numbers of peaks at  $\lambda \sim 520 \text{ nm}$  to that at 750 nm compared to the ratio of absorbance of bi-layer at these respective  $\lambda$ 's. This can be attributed to good electronic transport of perovskite. The peak at  $\lambda \sim 640 \text{ nm}$  can be due to the increased absorption of the bilayer with P3HT contributing to the photocurrent by producing free charge carriers due to dissociation of exciton created in P3HT (at absorption edge of P3HT) at the P3HT/Perovskite interface. EQE for  $\lambda < 640 \text{ nm}$  is a net result of photocarriers created in perovskite and P3HT and its effective transport across the device. Deviation of EQE spectra from absorption spectra for  $\lambda < 620 \text{ nm}$  can be attributed to reduced contribution from P3HT due to the creation of charge transfer excitons in P3HT. High energy photons are needed to dissociate this charge transfer excitons and this results in a EQE peak at  $\lambda \sim 485 \text{ nm}$ , which is blue shifted compared to the bilayer absorption peak. In the shorter wavelength region perovskite absorption prevails and it follows the absorption spectra. The observed increase in EQE of solar cells (in the  $\lambda$  range 400 nm to 650 nm) made with 40 wt% solution compared to that of 30 wt% solution can be due to increased absorption of perovskite layer made with 40 wt% solution. Most of the light in this spectral region have a penetration depth which is less than the thickness of the perovskite film due to an absorption coefficient of  $10^5 \text{ cm}^{-1}$ . It has been observed that the poor coverage of the perovskite film reduces light absorption in this spectral region. Hence the enhancement of EQE in this spectral

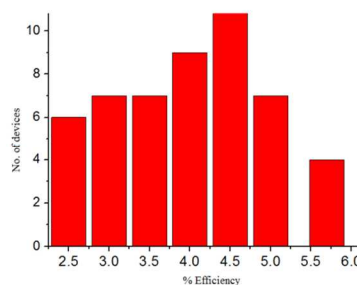


Figure 5. Histogram of number of devices with the corresponding power conversion efficiencies obtained.



region is due to the better coverage of perovskite films made from 40 wt% solution compared to that made from 30 wt% solutions. A histogram of PCE values of 50 different cells obtained in our lab is given for consistency and reproducibility in Figure 5.

The devices were stored in an air tight container and characterized after 50 days. The PCE dropped drastically to 0.11% with  $J_{sc}$  of 1.05 mA/cm<sup>2</sup>,  $V_{oc}$  of 323 mV and FF of 0.32. This shows the degradation of the device in humid air conditions. Furthermore, reduction in the performance of the device can be attributed to the silver electrodes which were found to have deteriorated with time, in accordance with the observation by Snaith et al.[34] and due to degradation of P3HT over time as seen from the UV-Vis spectrum studies. The halide ion in the perovskite can result in the degradation of the silver electrode to silver halides, thus adversely impacting the performance of the device. Various other top electrode such as gold and aluminium were used to replace Ag, but resulted in poor device performance with PCE less than 2%. It can be concluded that cell degradation is mainly caused by the oxidation of silver electrode and P3HT, over a period of time.

## Conclusions

Solid state dye sensitized solar cells based on an organic inorganic hybrid perovskite using  $CH_3NH_3Pb_{3-x}Cl_x$  is made with high performance and efficiency under highly humid and ambient air conditions by a spin coating method. Best performing FTO/TiO<sub>2</sub>/CH<sub>3</sub>NH<sub>3</sub>Pb<sub>3-x</sub>Cl<sub>x</sub>/P3HT/Ag solar cells processed with 40 wt% perovskite solutions showed a PCE of 5.67% with a  $J_{sc}$  of 18.85 mA/cm<sup>2</sup>, a  $V_{oc}$  of 640 mV and a FF of 0.407. The EQE showed contribution from both P3HT and perovskite, with P3HT collecting the unabsorbed light through perovskite due to its poor coverage. The XRD and UV Vis studies showed that the perovskite layer is stable for a period of one month. The observed degradation is attributed to a collective effect of P3HT degradation as observed in the UV-Vis studies and that due to Ag oxidation. Future studies are pursued to enhance the perovskite surface coverage as it is sensitive to the concentration of perovskite solution used for spin coating and annealing temperature.

## Acknowledgements

- 1)Department of Science and Technology (DST/TM/SERI/2k11/73(G)) Solar Energy Research Initiative project, Ministry of Human Resource Development and Govt. of India.
- 2)Amorphous Silicon Solar Cell Plant, Bharat Heavy Electricals Limited, Gurgaon, India,

## Notes and references

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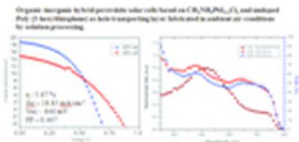
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Organic -Inorganic hybrid perovskite solar cells based on  $\text{CH}_3\text{NH}_3\text{PbI}_{3-x}\text{Cl}_x$  and undoped Poly (3-hexyl thiophene) as the hole transporting layer fabricated in ambient air conditions by solution processing 12x6mm (300 x 300 DPI)

